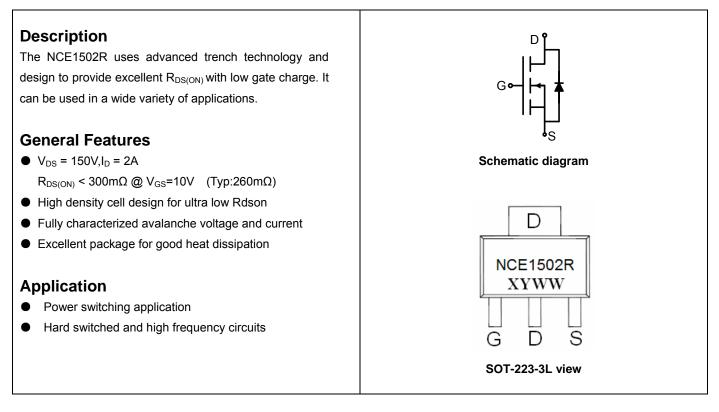


# NCE N-Channel Enhancement Mode Power MOSFET



#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE1502R	NCE1502R	SOT-223-3L	Ø330mm	12mm	2500 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	150	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	I <sub>D</sub>	2	A	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	6	A	
Maximum Power Dissipation	PD	2	W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C	

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ extsf{ heta}JA}$	62.5	°C/W

#### **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	150	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μA



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# NCE1502R

Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)					•	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	1.5	2.0	2.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =1.5A	-	260	300	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =15V,I <sub>D</sub> =1.5A	-	3	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	)/ -25)/)/ -0)/	-	235	-	PF
Output Capacitance	C <sub>oss</sub>	- V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, - F=1.0MHz	-	36	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	20	-	PF
Switching Characteristics (Note 4)	·			•		
Turn-on Delay Time	t <sub>d(on)</sub>		-	8	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =75V,I <sub>D</sub> =1A,R <sub>L</sub> =75Ω	-	10	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =6Ω	-	20	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg		-	8		nC
Gate-Source Charge	Q <sub>gs</sub>	$-V_{DS}=75V,I_{D}=1.5A,$	-	1.4	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	2.1	-	nC
Drain-Source Diode Characteristics		-			•	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =2A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	2	А

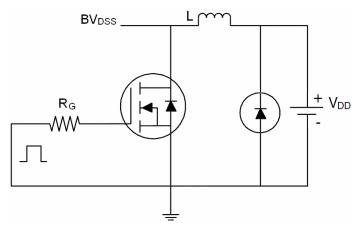
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to product

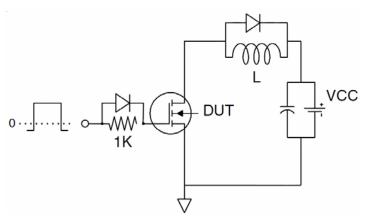


# Test Circuit

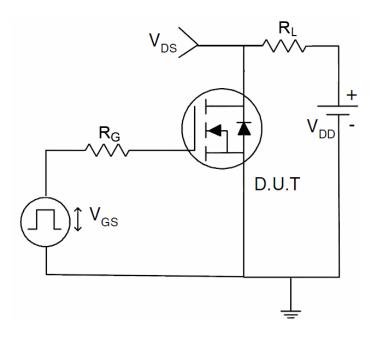
1) E<sub>AS</sub> Test Circuit



#### 2) Gate Charge Test Circuit



#### 3) Switch Time Test Circuit





75

6

8

T<sub>J</sub> = 25 °C

1.0

0.8

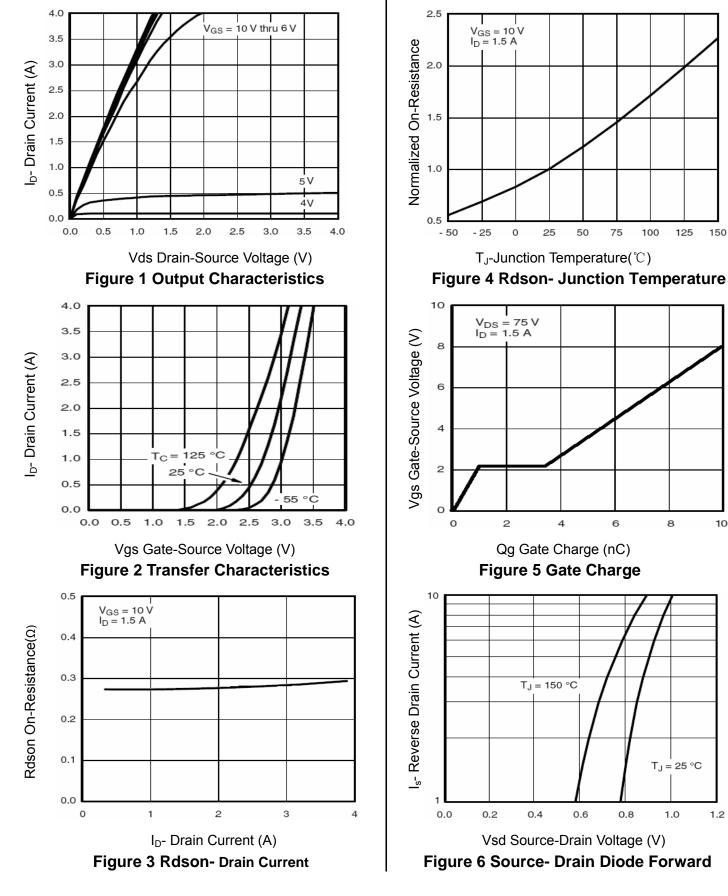
10

100

125

150

## **Typical Electrical and Thermal Characteristics (Curves)**



1.2



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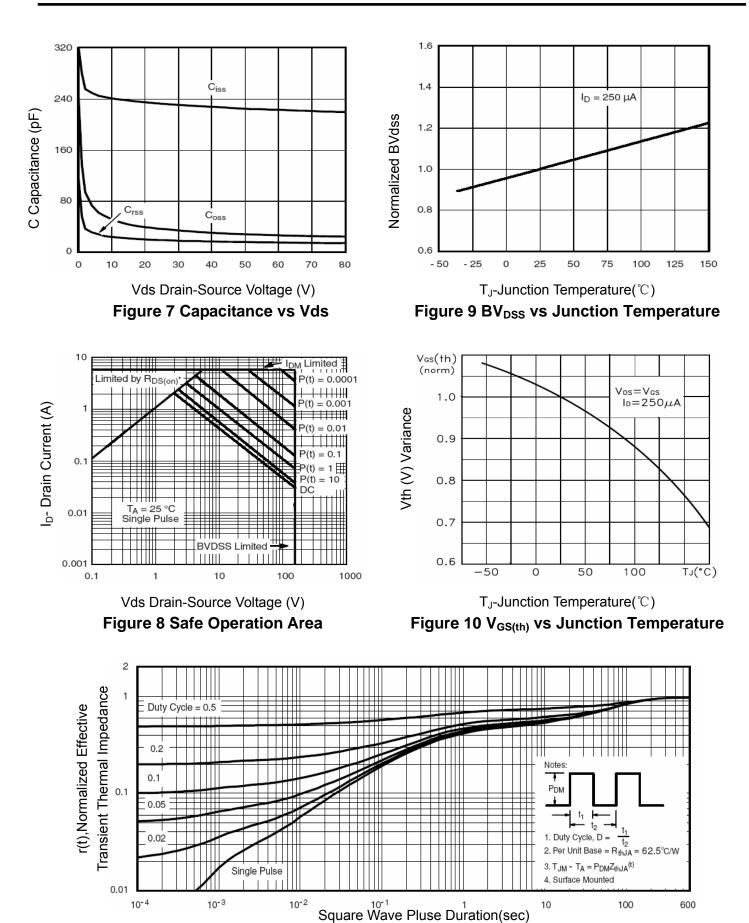
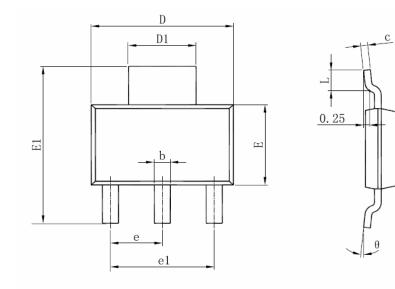


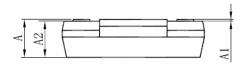
Figure 11 Normalized Maximum Transient Thermal Impedance



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### SOT-223-3L Package Information





Querra la	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.820	0.026	0.032	
с	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
е	2.300(BSC)		0.091(BSC)		
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

#### Notes

1. All dimensions are in millimeters.

- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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